



# Product data sheet

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SOT-143

#### Features

- 150Watts peak pulse power (tp = 8/20µs)
- Tiny SOT143 package
- Bidirectional configurations
- Solid-state silicon-avalanche technology
- Low clamping voltage
- Low leakage current
- Low capacitance (Cj=1.5pF typ I/O to I/O.)
- Protection one data/power line to:
- IEC 61000-4-2 ±15kV contact ±20kV air
- IEC 61000-4-4 (EFT) 40A (5/50ns)
- IEC 61000-4-5 (Lightning) 5A (8/20µs)

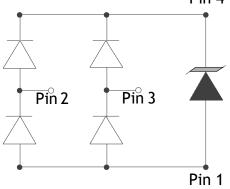
#### **Mechanical Data**

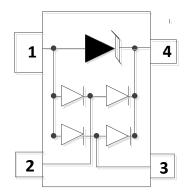
- SOT143 package
- Molding compound flammability rating: UL94V-0
- Packaging: Tape and Reel
- RoHS/WEEE Compliant

#### **Applications**

- USB2.0,
- Ethernet
- Notebooks, Desktops, and Servers
- Video Line Protection

# Pin 4





# Schematic & PIN Configuration



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### **Absolute Maximum Rating**

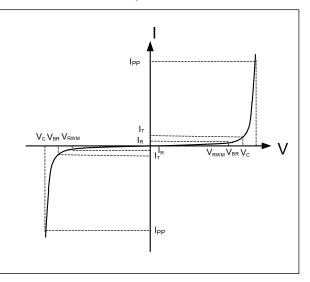
Rating	Symbol	Value	Units	
Peak Pulse Power ( t <sub>p</sub> =8/20µs )	P <sub>PP</sub>	150	Watts	
Peak Pulse Current ( t <sub>p</sub> =8/20µs ) (note1)	I <sub>pp</sub>	5	A	
ESD per IEC 61000-4-2 (Air) ESD per IEC 61000-4-2 (Contact)	V <sub>ESD</sub>	20 15	kV	
Lead Soldering Temperature	ΤL	260(10seconds)	C	
Junction Temperature	TJ	-55 to + 125	Ĉ	
Storage Temperature	T <sub>stg</sub>	-55 to + 125	Ĵ	

# **Electrical Characteristics**

Parameter	Symbol	Conditions	Min	Typical	Мах	Units
Reverse Stand-Off Voltage	$V_{RWM}$				5.5	V
Reverse Breakdown Voltage	$V_{BR}$	I <sub>T</sub> =1mA	6.0			V
Reverse Leakage Current	I <sub>R</sub>	V <sub>RWM</sub> =5V,T=25℃			500	nA
Clamping Voltage	V <sub>C</sub>	I <sub>PP</sub> =5A,t <sub>p</sub> =8/20µs		14		V
Junction Capacitance	Cj	V <sub>R</sub> = 0V, f = 1MHz IO to IO		1.5		- pF
		V <sub>R</sub> = 0V, f = 1MHz IO to GND		1.0	2.0	

# Electrical Parameters (TA = 25°C unless otherwise noted)

Symbol	Parameter
Ірр	Maximum Reverse Peak Pulse Current
Vc	Clamping Voltage @ IPP
VRWM	Working Peak Reverse Voltage
IR	Maximum Reverse Leakage Current @ Vким
Vbr	Breakdown Voltage @ I⊤
Iτ	Test Current



Note:. 8/20µs pulse waveform.





# **Typical Characteristics**

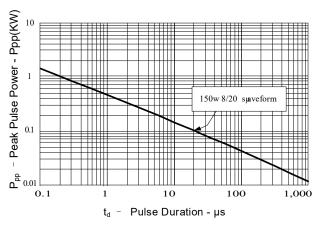


Figure 1: Peak Pulse Power vs. Pulse Time

Figure3: Pulse Waveform

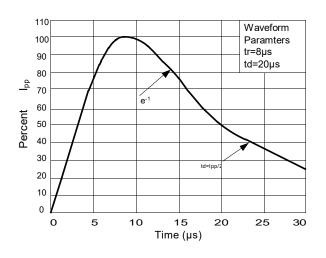


Figure 2: Power Derating Curve

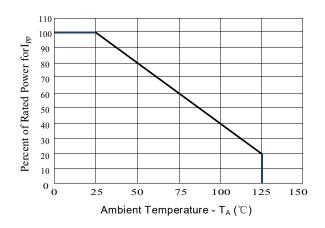
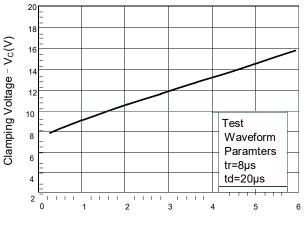


Figure 4: Clamping Voltage vs.lpp



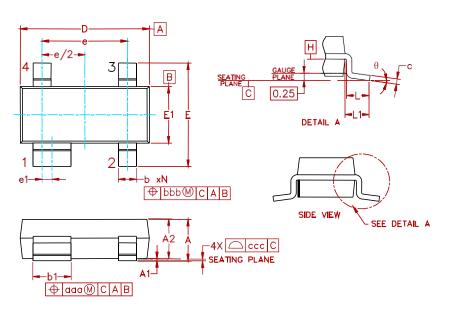
Peak Pulse Current - IPP (A)



CM1293A-02SR HF 🐼

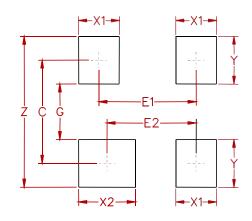
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#### PACKAGE MECHANICAL DATA



Cumple of	Inches			Millimeters			
Symbol	Min.	Nom.	Max.	Min.	Nom.	Max.	
Α	0.031	-	0.048	0.80	-	1.22	
A1	0.000	-	0.008	0.013	-	0.15	
A2	0.020	0.035	0.042	0.75	0.90	1.07	
b	0.011	-	0.020	0.30	-	0.51	
b1	0.029	-	0.037	0.76	-	0.94	
с	0.003	-	0.008	0.08	-	0.20	
D	0.110	0.114	0.120	2.80	2.90	3.04	
Е	0.082	0.093	0.104	2.10	2.37	2.64	
E1	0.047	0.051	0.055	1.20	1.30	1.40	
е	0.075			1.92 BSC			
e1	0.008			0.20 BSC			
L	0.015	0.020	0.024	0.40	0.50	0.60	
L1	(0.021)			(0.54)			
Ν	4			4			
θ	0°	-	8°	0°	-	8°	
aaa	0.006			0.15			
bbb	0.008			0.20			
ссс	0.004			0.10			

# Suggested Pad Layout



#### **REEL SPECIFICATION**

P/N	PKG	QTY	
CM1293A-02SR	SOT-143	3000	



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